

ER3AF THRU ER3JF

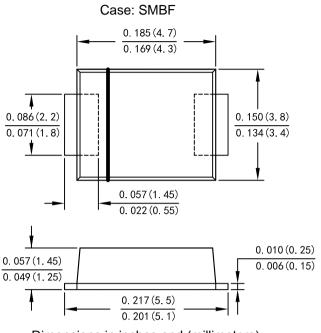
3.0AMP Surface Mount Superfast Rectifiers

Features

- · Glass passivated junction chip
- · Low Power Loss, High Efficiency
- · Ideally Suited for Automatic Assembly
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V- 0

Mechanical Data

- · Case: Molded plastic SMBF
- Terminals: Plated leads solderable per MIL-STD-750,Method 2026 guaranteed
- · Polarity: Color band dentes cathode end
- · Mounting Position: Any
- · Making: Type Number



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load

For capacitive load derate current by 20%

Type Number	SYMBOL	ER3AF	ER3BF	ER3CF	ER3DF	ER3EF	ER3GF	ER3JF	Unit
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	150	200	300	400	600	V
Maximum RMS Voltage	VRMS	35	70	105	140	210	280	420	V
Maximum DC Blocking Voltage	VDC	50	100	150	200	300	400	600	V
Average Rectified Output Current @T∟=100°C	IF(AV)	3.0							А
Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	Ігѕм	110							А
I ² t Rating for Fusing (t < 8.3ms)	l²t	26.56							A ² S
Forward Voltage @IF=3.0A	VFM	0.95 1.3 1.7					1.7	V	
Peak Reverse Current @T _A =25 °C	5.0								uA
At Rated DC Blocking Voltage @T₄ =125 ℃	I _R	100							
Maximum Reverse Recovery Time (Note 1)	Trr	35							ns
Typical Junction Capacitance (Note 2)	CJ	53 35 25					25	pF	
Typical Thermal Resistance Junction to Ambient	R0 JA	65							°C/W
Operating Temperature Range	TJ	-55 to+150							°C
Storage Temperature Range	Тѕтс	-55 to +150							°C

Note:

1.Reverse Recovery Test Conditions:IF=0.5A,IR=1.0A,IRR=0.25A.

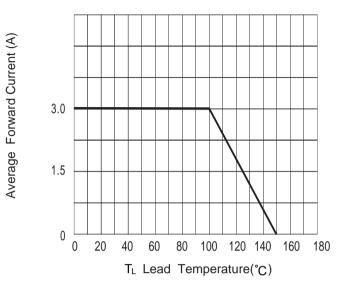
2. Measured at 1.0 MHz and Applied reverse Voltage of 4.0V D.C.

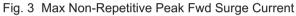


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Fig. 1 Forward Current Derating Curve





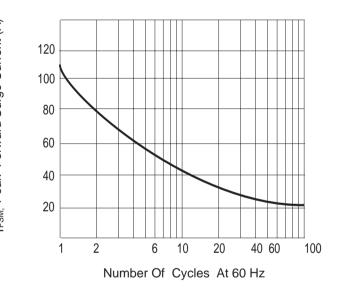


Fig.5 Typical Reverse Chracteristics

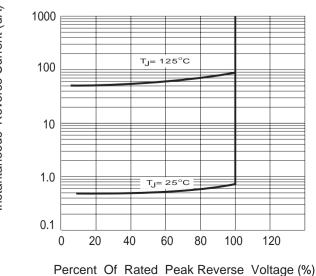
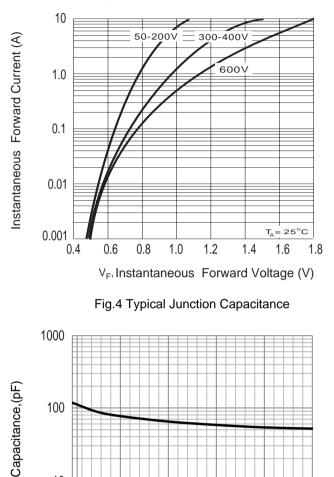


Fig. 2 Typ. Forward Characteristics



100

10

1.0 0

1

V_R, Reverse Voltage (V)

3

2

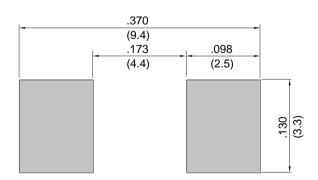
TJ= 25 ℃

f= 1.0MHz Vsig = 50mVp-p

4

5

Fig.6 Mounting PAD Layout



IFSM, Peak Forward Surge Current (A)

Instantaneous Reverse Current (uA)



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